Multilayer black phosphorus as saturable absorber for an Er:Lu$_2$O$_3$ laser at $\sim$3 $\mu$m

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Multilayer black phosphorus (BP) nanoplatelets of different thicknesses were prepared by the liquid phase exfoliation method and deposited onto yttrium aluminum garnet substrates to form saturable absorbers (SAs). These were characterized with respect to their thickness-dependent saturable absorption properties at 3 $\mu$m. The BP-SAs were employed in a passively Q-switched Er:Lu$_2$O$_3$ laser at 2.84 $\mu$m. By using BP exfoliated in different solvents, stable pulses as short as 359 ns were generated at an average output power of up to 755 mW. The repetition rate in the experiment was 107 kHz, corresponding to a pulse energy of 7.1 $\mu$J. These results prove that BP-SAs have a great potential for optical modulation in the mid-infrared range. © 2016 Chinese Laser Press

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1. INTRODUCTION

The research in newly emerging saturable absorber (SA) materials primarily focuses on graphene and graphene-like two-dimensional (2D) materials [1–4]. Compared with conventional SAs, such as semiconductor SA mirrors and ion-doped crystals [5,6], these new nanomaterials are favorable for many applications due to their fascinating advantages of broadband saturable modulation, controllable modulation depth, and ultrafast recovery time [7]. However, there is still a bottleneck in the field of modulated mid-infrared (mid-IR) lasers based on 2D-SAs. Graphene suffers from the intrinsic limitation of its zero-bandgap structure, which increases the nonsaturable optical absorption (∼2.3% per layer) [8]. For other effective 2D-SAs such as topological insulators like Bi$_2$Te$_3$, Bi$_2$Se$_3$, and Sb$_2$Te$_3$ [9], the complex preparation process severely limits their application in photonics and optoelectronics. Finally, in semiconducting transition metal dichalcogenides, such as molybdenum disulfide (MoS$_2$), the optical response is mainly confined to the visible and near-IR range, due to their comparatively large bandgap (MoS$_2$-monolayer: direct bandgap of 1.86 eV; MoS$_2$-bulk: indirect gap of 0.86–1.29 eV) [10].

Black phosphorus (BP), a novel class of 2D materials, has a direct bandgap, which depends on the number of layers and decreases with increasing thickness, ranging from ∼2.0 eV (monolayer) to ∼0.3 eV (bulk) [11]. This unique feature makes it a promising candidate for photonics applications in a broad wavelength range between 0.6 and 4.1 $\mu$m. So far, BP-SAs have been widely employed as modulators in passively Q-switched or mode-locked lasers at 1 and 2 $\mu$m [12–15]. At 3 $\mu$m only one report by Kong et al. can be found, who realized a pulsed bulk laser with a very long pulse duration of 4.5 $\mu$s [16]. Except for this, only a few relevant studies on BP modulated fiber lasers in this wavelength range have been reported [17,18].

In 1967, Robinson and Devor demonstrated the first Er$^{3+}$-doped laser at 3 $\mu$m on the $^4$I$_{11/2} \rightarrow ^4I_{13/2}$ transition [19]. However, it proved difficult to optimize the performance of Er$^{3+}$-doped 3-$\mu$m lasers due to the severe thermal effects, which are induced by the low Stokes efficiency (∼35%) and the strong multiphonon relaxation. The cubic rare-earth sesquioxide crystals, with high thermal conductivity and low phonon energies [20,21], have been proven to be suitable host materials for mid-IR lasers. In previous works, up to 14 W of laser output around 3 $\mu$m have been generated with Er:Y$_2$O$_3$ at cryogenic temperatures [22], and at room temperature 5.9 W of continuous wave (CW) laser output were realized with Er:Lu$_2$O$_3$ [23]. Recently, we demonstrated an efficient passively Q-switched Er:Lu$_2$O$_3$ laser using stoichiometric-defect MoS$_2$-SA, which generated the shortest pulses of any 2D-SA Q-switched 3 $\mu$m laser with more than 1 W of average output power [24].

Pulsed lasers around 3 $\mu$m, which is well within the eye-safe region and can be strongly absorbed by water, are sought after in biomedical applications [25]. Besides, such lasers also have particularly practical value in mid-IR optical parametric oscillators and generation of terahertz (THz) and IR supercontinuum light [26,27].

In this contribution, we prepared multilayer BP nanoplatelets based on the liquid phase exfoliation (LPEX) method and...
of up to 7.1 μm and a pulse duration of 359 ns and a pulse energy of 755 mW with a pulse energy of up to 7.1 μJ.

2. PREPARATION AND CHARACTERIZATION OF BP-SAS

BP is a room-temperature stable orthorhombic modification of phosphorus, which exhibits a graphite-like layer structure [28] and gives rise to saturable absorption properties which strongly depend on the number of layers. LPEx is an effective method for the fabrication of such multilayer structures, in which the choice of a proper solvent plays a key role. In order to prepare high quality BP nanoflakes of different thicknesses, both pure isopropyl alcohol (IPA) and saturated NaOH N-methyl-2-pyrrolidone (NMP) solvent were used in our experiment [12,29]. In both cases, exfoliation could be obtained by adding bulk BP into the selected solvent and ultrasonication for 6 h. After centrifugation at 1500 rpm for 10 min, the top two-thirds of the dispersions were collected for further processing. Since NMP has a poor volatility, the multilayer BP nanoplatelets exfoliated by saturated NaOH NMP solvent were additionally separated and rediluted in ethanol (EtOH) solution to remove the remaining Na3+-ions.

For a systematic characterization of the structure and morphology of the BP samples, transmission electron microscopy (TEM) and Raman spectroscopy were utilized. As shown in Figs. 1(a) and 1(b), the TEM pictures clearly prove that the as-prepared BP nanoplatelets have sheet-like structures with submicrometer dimensions. The Raman spectra shown in Fig. 1(c) were measured by using a HeNe laser at 632.8 nm. One out-of-plane vibration mode (A1g) and two in-plane vibration modes (B2g and A2g) were detected. Compared to the BP-bulk curve, all three peaks in BP-IPA and BP-EtOH curves exhibit a blueshift. The A2g vibration mode is more sensitive to the number of layers; therefore the distance between A2g and A1g modes changes for samples of different thickness. These Raman shifts indicate a decreased thickness compared to the bulk material and thus the successful exfoliation of BP samples [29,30]. Furthermore, the characteristic peaks of the BP-EtOH curve at 362.1, 439.8, and 1467.4 cm−1 show a stronger blueshift than the BP-IPA peaks at 361.9, 438.7, and 1466.2 cm−1, which is a first indicator for a lower number of layers in the samples prepared in BP-EtOH.

Atomic force microscopy (AFM) was used to precisely analyze the thickness of the BP dispersed in the different solvents [see Figs. 2(a) and 2(b)]. Assuming a single layer thickness of ~0.6 nm of BP [31], the number of layers of the BP nanoplatelets exfoliated in IPA was calculated to be between 28 and 52, whereas the platelets dissolved in EtOH exhibit a thickness of only 19–35 layers. The lower thickness of the BP-EtOH compared to the BP-IPA is in good agreement with the results of TEM and Raman measurements.

Fourier transform IR (FT-IR) absorption spectra were recorded to analyze the broadband absorption capability of the BP. As shown in Fig. 3(a), the BP-EtOH film coating on a YAG substrate with dimensions of 40 mm x 20 mm exhibits a gradually decreasing absorption in the whole wavelength range from 0.8 to 3.3 μm.

BP-SAs were fabricated by dripping the BP dispersions onto round YAG substrates with a radius of 0.5 in. (1.27 cm) and drying in a vacuum oven at room temperature for 10 h. Unlike the samples used in TEM and AFM, for which a tiny amount of dispersion is preferred in that BP nanoplatelets could be clearly observed and measured, the dosage for BP-SAs could only be optimized according to the results of the laser experiment.

We performed small-signal transmission measurements for the BP-SAs used in the laser experiments. For this purpose we used a CW Er:Lu2O3 laser [24]. The resulting values for the BP-IPA-SA and the BP EtOH-SA were 78% and 82.6%, respectively. The mismatch of the unsaturated absorption compared to the FT-IR measurement shown in Fig. 3(a) results from a different BP-nanoplatelet density on the two different substrates used for the respective experiments. Besides, the FT-IR spectra were corrected for Fresnel reflection, which was not possible.
for the CW Er:Lu$_2$O$_3$ due to Fabry–Perot effects in the plane-parallel YAG substrates of the SAs. The nonlinear optical response of the BP-SAs was investigated using a $\sim$100 ns Q-switched Er:Lu$_2$O$_3$ laser at 2.84 $\mu$m as shown in Figs. 3(b) and 3(c) [24]. One can recognize a significant difference in the saturable absorption between the samples prepared in IPA and EtOH, which we attribute to the different thickness of the BP nanoplatelets. The modulation depths of the BP-IPA-SA and the BP-EtOH-SA were estimated to be 8.0% and 5.0%, respectively. This is in line with the different thicknesses of the BP nanoplatelets prepared in both solvents. Considering the ultrafast recovery time of $24 \pm 2$ fs in BP [32], there was less meaning in assessing the saturation fluence with a submicrosecond pulsed source. The saturated transmission of the BP-IPA-SA and the BP-EtOH-SA amounted to 87.1% and 89.8%, respectively; however, the uncoated YAG substrates exhibit a transmission of only 93.2% due to surface reflection, which, however, does not represent losses when inserted perfectly perpendicular to the beam into a laser cavity. Accordingly, the nonsaturable loss of BP-IPA and BP-EtOH films were estimated to be 6.1% and 3.4%, respectively. The lower nonsaturable losses of the BP-EtOH-SA compared with BP-IPA-SA can be attributed to the decrease of the BP concentration induced by the redilution process.

These results are well suited for the application of these samples as SAs in our Er:Lu$_2$O$_3$ laser and prove that BP layers of different thickness have a great potential to cover a large parameter range, which makes them suitable also for other laser systems in this wavelength range.

3. LASER EXPERIMENT

A. Experimental Setup

The Er:Lu$_2$O$_3$ crystal prepared for our experiment had an Er$^{3+}$ concentration of 7 at. % and dimensions of 3 mm $\times$ 3 mm $\times$ 8 mm. It has already been proved to be an excellently suited gain medium for efficient high-power lasing at 3 $\mu$m [23,24]. The Er:Lu$_2$O$_3$ crystal was wrapped in indium foil and embedded in a cooper block water-cooled to 10$^\circ$C. The cavity for the laser experiments on passive Q-switching using our BP-SAs was a simple, 2.5-cm-long compact linear cavity, as schematically presented in Fig. 4. A fiber-coupled laser diode with 200 $\mu$m core diameter and a numerical aperture of 0.22 was taken as the pump source. The emission wavelength could be adjusted by changing the diode temperature to match the absorption peak of Er:Lu$_2$O$_3$ at 974 nm, while preventing wavelengths of strong exited-state absorption [23]. The pump beam was focused into the gain medium with a spot diameter of 400 $\mu$m. The flat incoupling mirror $M_1$ was antireflection coated for 974 nm (T $>$ 90%) and high-reflection coated for the laser wavelength range between 2.7 and 2.9 $\mu$m (R $>$ 99%). Flat mirrors with transmission values of 1%, 3%, and 5% at 2.85 $\mu$m were employed as the output coupling mirror $M_2$. The BP-SA-films on YAG substrates were placed in the beam near $M_2$. The mode radius on the SA was estimated to be $\sim$300 $\mu$m. In order to block the residual pump light, a filter was put behind $M_2$. The average output power was measured by a PM100D power meter with an S314C power head (Thorlabs Inc., USA). The emission spectrum was detected by an InSb infrared detector (DInSb5-De01, Zolix, China) and analyzed with a grating spectrometer (Omni-2000, Zolix, China). The temporal evolution of the laser pulse trains was monitored by a DPO 7104C digital phosphor oscilloscope with a rise time of 350 ps (1 GHz bandwidth and 20 GS/s sampling rate, Tektronix Inc., USA), combined with a fast HgCdTe IR detector with a response time of 20 ns (PVI-2TE-5, Vigo System S.A.)

B. Results and Discussion

Stable Q-switched laser operation could be achieved with either BP-SA in the cavity. Figure 5 shows the Q-switched laser characteristics for both cases. Employing the BP-IPA sample, the threshold pump powers were 1.09, 1.41, and 1.91 W at T = 1%, 3%, and 5%, respectively. Increasing the absorbed pump power to 5.91 W, the highest average output power of 755 mW was obtained at T = 3% with a slope efficiency of 17.9%. By optimizing the technology of mirror-coating and cooling the crystal and SA with nitrogen, the investigation realizing higher slope efficiency can be expected. In addition, at even higher pump power levels, the Q-switched pulse train became unstable and finally went into CW mode. By reducing the pump power, the laser switched back into Q-switched operation. This phenomenon, known as overbleaching of the SA [33], occurred as the CW intracavity power was high enough to saturate the absorber. For this reason, the significant increase in maximum output power becomes particularly difficult. The BP-EtOH Q-switched laser exhibits a slightly lower threshold and a marginally higher
Figure 5. Average output power of the Q-switched Er:Lu₂O₃ laser using BP-SA; insets (a) and (c) display the output laser spectra, and insets (b) and (d) describe the output fluctuations versus time.

Figure 6. Top: pulse repetition rate and pulse duration versus absorbed pump power for different output coupler transmissions; bottom: temporal traces of Q-switched pulse train utilizing BP-IPA SA at T = 3%.

The laser emission spectra are presented in the insets (a) and (c) of Fig. 5. The center wavelengths of both lasers were fixed to 2.84 μm. Besides, the fluctuations of the two lasers were detected for 40 min at the maximum output power, as shown in the insets (b) and (d) of Fig. 5. The stability of both lasers was quite comparable to the results presented in [24], where MoS₂ was used as the SA. This indicates that the instability is not attributed to the properties of the BP-SAs but is intrinsic to the complex transition processes in the Er³⁺ ion.

Figure 6 depicts the pulse characteristics versus pump power and output coupler transmission in detail. The pulse repetition rate increases with absorbed pump power, while the pulse duration exhibits an opposite trend. At identical pump power levels, the BP-EtOH-based film generated shorter pulses of 439 ns at a higher repetition rate of 92 kHz. However, the shortest pulse duration of 359 ns at a repetition rate of 107 kHz was obtained by using the BP-IPA-SA under an absorbed pump power of 5.91 W at T = 3%. The pulse train and the temporal profile of a single pulse are shown as an example in the lower part of Fig. 6. The pulse-to-pulse instability was found to be below 10%, which indicates that the BP-IPA film is still working quite stably at an average power as high as 755 mW.

Table 1 summarizes the results obtained with other 2D-SA Q-switched lasers in the 3-μm wavelength range compared to our result. It should be noticed that, excepting the SAs, the pulse duration was also strongly influenced by cavity design and laser parameters. The pulse durations generated in this work are much shorter than those obtained by graphene and Bi₂Te₃ SAs, and are comparable to the results generated by MoS₂ SAs. The compact cavity design in this work made a contribution to compressing the pulses. This comparison also illustrates that the YAG-based BP-IPA film is suitable for Q-switched solid-state 3 μm lasers, while the BP-EtOH film or the thinner BP nanoflakes might enable mode-locking of Er³⁺-doped lasers at 3 μm. Experiments in this respect are in progress.

Figure 7 depicts the pulse energies and peak powers, which both increased with the absorbed pump power. The Er:Lu₂O₃ crystal had absorbed about 90% pump power, and the two samples worked well during the laser experiments, even under the available high power levels. At T = 3%, the maximum single pulse energies were 7.1 and 5.3 μJ, respectively. Assuming a Gaussian pulse shape, which is justified by the measured pulse shape shown in Fig. 6, the highest peak power of 18.6 W was obtained at T = 3% with the BP-IPA-SA.

4. CONCLUSION

In conclusion, multilayer BP nanoplatelets were prepared based on the LPEx method, and BP-SAs were fabricated by spreading the dispersions over YAG substrates. The layer-dependent saturable absorption properties near 3 μm were experimentally demonstrated. Stable BP-IPA and BP-EtOH

<table>
<thead>
<tr>
<th>Type of SA</th>
<th>Graphene</th>
<th>Bi₂Te₃</th>
<th>BP-SAM</th>
<th>BP Gold-Film Mirror</th>
<th>MoS₂</th>
<th>BP-IPA</th>
<th>BP-EtOH</th>
</tr>
</thead>
<tbody>
<tr>
<td>Gain medium</td>
<td>Er³⁺-fiber</td>
<td>Ho³⁺-fiber</td>
<td>Er³⁺-fiber</td>
<td>Er₂O₃ ceramic</td>
<td>Er:Lu₂O₃ crystal</td>
<td>Er:Lu₂O₃ crystal</td>
<td>Er:Lu₂O₃ crystal</td>
</tr>
<tr>
<td>Wavelength (μm)</td>
<td>2.78</td>
<td>2.98</td>
<td>2.78</td>
<td>2.72</td>
<td>2.84</td>
<td>2.84</td>
<td>2.84</td>
</tr>
<tr>
<td>Max. output power (mW)</td>
<td>62</td>
<td>327.4</td>
<td>485</td>
<td>6</td>
<td>1630</td>
<td>755</td>
<td>489</td>
</tr>
<tr>
<td>Max. repetition rate (kHz)</td>
<td>37</td>
<td>82</td>
<td>63</td>
<td>12.6</td>
<td>121</td>
<td>107</td>
<td>92</td>
</tr>
<tr>
<td>Shortest pulse duration (μs)</td>
<td>2.9</td>
<td>1.37</td>
<td>1.18</td>
<td>4.47</td>
<td>0.335</td>
<td>0.359</td>
<td>0.430</td>
</tr>
<tr>
<td>Reference</td>
<td>[34]</td>
<td>[35]</td>
<td>[16]</td>
<td>[18]</td>
<td>[24]</td>
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</tr>
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passively Q-switched Er:Lu$_2$O$_3$ laser operation at 2.84 μm was realized. The minimum pulse duration of 359 ns was obtained at the highest average output power of 755 mW, corresponding to a pulse energy of 7.1 μJ. The results validate that BP is a promising optical modulator for mid-IR pulse lasers and has great potential in ultrafast photonics applications.

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